Application No.: 10/028,768 Attorney Docket No. 2658-0281P
Art Unit: 2815 Amendment filed March 23, 2004

Page 2 of 15

Amendments to the Claims

1. (Currently Amended) A liquid crystal display device, comprising:

a substrate;

a gate electrode over the substrate;

a first semiconductor layer over the substrate; and

a source electrode and a drain electrode over the first semiconductor

layer, the source and drain electrodes having a first metal layer and a second

metal layer formed in a same pattern and a defining a separation between the

source electrode and drain electrode,

wherein the first metal layer is patterned using the second metal layer as a

mask.

2. (Currently Amended) The device of claim 1, further comprising:

a gate insulating film over the gate electrode and between the substrate and

the first semiconductor layer;

a second semiconductor layer between the first metal layer and the first

semiconductor layer, the second semiconductor layer defining a portion of the

separation region in the same pattern as the first and second metal layers;

a protective layer over the source and drain electrodes; and

a pixel electrode provided on the protective layer.

Application No.: 10/028,768 Attorney Docket No. 2658-0281P
Art Unit: 2815 Amendment filed March 23, 2004

Page 3 of 15

3. (Original) The liquid crystal display device as claimed in claim 1, wherein the first metal layer includes molybdenum (Mo) or titanium (Ti).

4. (Original) The liquid crystal display device as claimed in claim 1, wherein the second metal layer includes aluminum (Al), an Al alloy, copper (Cu) or a Cu alloy.

5. (Original) A liquid crystal display device, comprising:

a substrate;

a gate electrode over the substrate;

a first semiconductor layer over the gate electrode;

a source electrode and a drain electrode over the first semiconductor layer, the source electrode and drain electrode including a first layer and a second layer patterned to form a separation region between the source and drain electrodes; and

a second semiconductor layer beneath the first metal layer and having a same pattern as the first metal layer.

6. (Original) The device of claim 5, further comprising:

a gate insulating film over the gate electrode;

a protective layer over the source and drain electrodes; and

a pixel electrode over the protective layer.

Application No.: 10/028,768 Attorney Docket No. 2658-0281P

Art Unit: 2815 Amendment filed March 23, 2004

Page 4 of 15

7. (Original) The liquid crystal display device as claimed in claim 5, wherein

the first metal layer includes Molybdenum (Mo) or titanium (Ti).

8. (Original) The liquid crystal display device as claimed in claim 5, wherein

the second metal layer includes aluminum (Al), an Al alloy, copper (Cu) or Cu

alloy.

9-20. (Canceled)

21. (New) The liquid crystal display device as claimed in claim 1, further

comprising an ohmic contact layer over the first semiconductor layer, wherein

inner edges of said ohmic contact layer facing said separation space are aligned

with inner edges of said first metal layer.

22. (New) The liquid crystal display device as claimed in claim 5, further

comprising an ohmic contact layer over the first semiconductor layer, wherein

inner edges of said ohmic contact layer facing said separation space are aligned

with inner edges of said first layer.

23. (New) A liquid crystal display device, comprising:

a substrate;

a gate electrode over the substrate;

a first semiconductor layer over the substrate;

an ohmic contact layer over the first semiconductor layer; and

Application No.: 10/028,768 Attorney Docket No. 2658-0281P

Art Unit: 2815 Amendment filed March 23, 2004

Page 5 of 15

a source electrode and a drain electrode over the first semiconductor layer,

the source and drain electrodes having a first metal layer and a second metal

layer formed in a same pattern and a defining a separation between the source

electrode and drain electrode,

wherein inner edges of said ohmic contact layer facing said separation

space are aligned with inner edges of said first metal layer.

24. (New) The device of claim 23, further comprising:

a gate insulating film over the gate electrode and between the substrate and

the first semiconductor layer;

a second semiconductor layer between the first metal layer and the first

semiconductor layer, the second semiconductor layer defining a portion of the

separation region in the same pattern as the first and second metal layers;

a protective layer over the source and drain electrodes; and

a pixel electrode provided on the protective layer.

25. (New) The liquid crystal display device as claimed in claim 23, wherein

the first metal layer includes molybdenum (Mo) or titanium (Ti).

26. (New) The liquid crystal display device as claimed in claim 23, wherein

the second metal layer includes aluminum (Al), an Al alloy, copper (Cu) or a Cu

alloy.